NSN 5961-01-103-4878

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Inclosure Material:

Plastic

Overall Length:

0.880 inches

Overall Height:

0.175 inches

Overall Width:

0.410 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-202

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

300.0 collector to emitter voltage/static/base open and 300.0 collector to base voltage/static/emitter open and 6.0 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

0.50 amperes source cutoff current and 250.00 milliamperes source cutoff current

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

80131-release6588 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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